



Article

Single-atom anchored g-C₃N₄ monolayer as efficient catalysts for nitrogen reduction reaction

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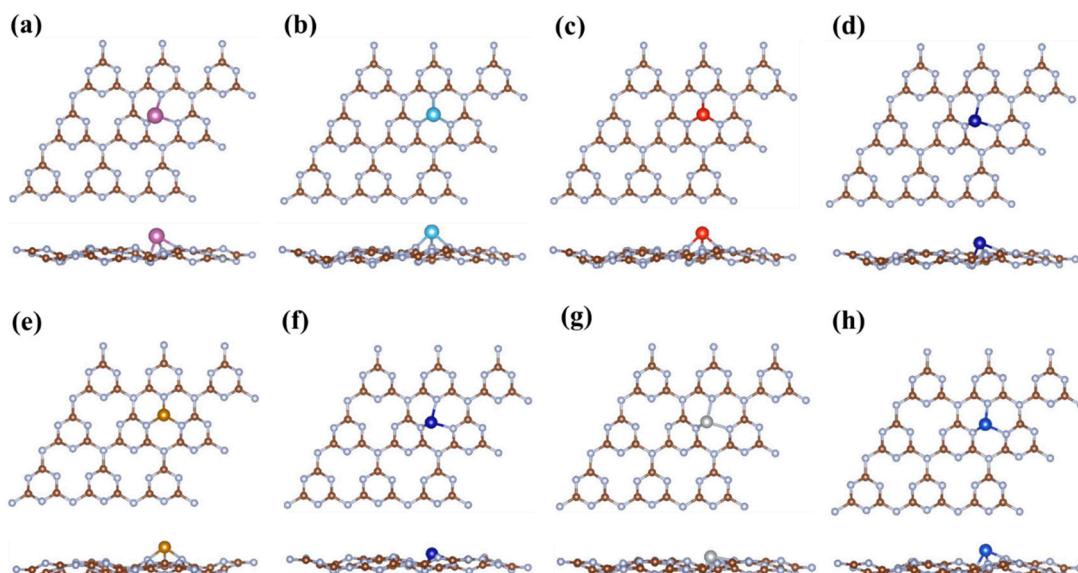


Figure S1. (a)-(h) Stable configurations of TM@g-C₃N₄ (TM= Sc, Ti, V, Cr, Fe, Co, Ni, Cu).

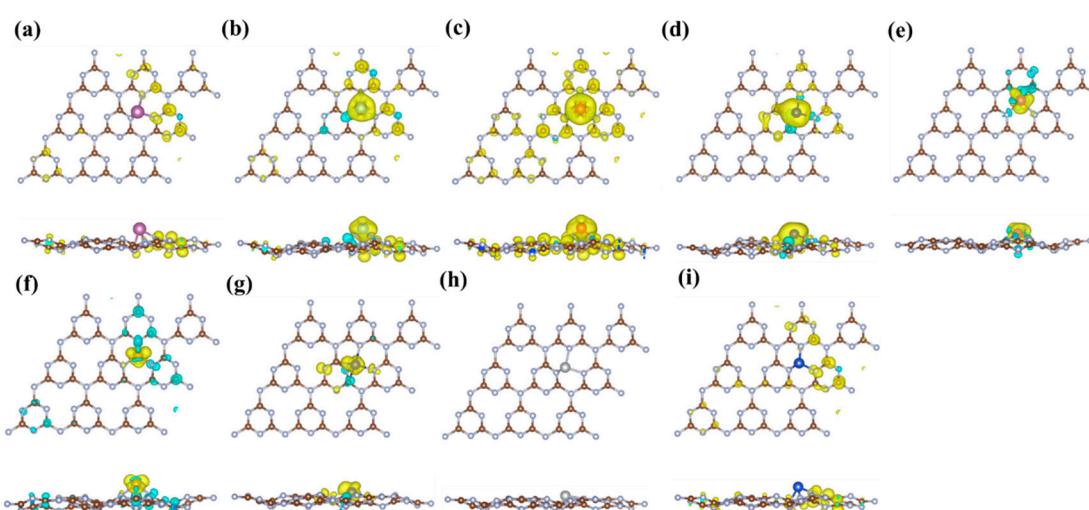


Figure S2. (a)-(i) Spin electron distributions of TM@g-C₃N₄ (TM= Sc-Cu) with isosurface 0.004 e/Bohr³. Yellow and blue represent spin-up and spin-down states.

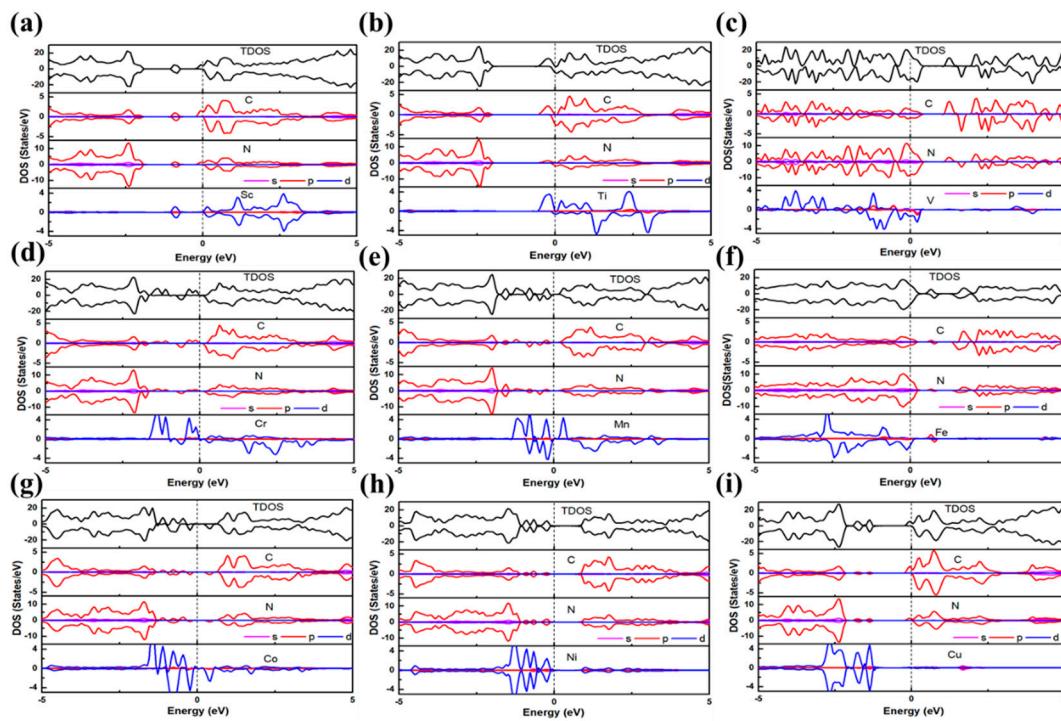


Figure S3. (a)-(i) DOS of TM@g-C₃N₄ (TM= Sc, Ti, V, Cr, Mn, Fe, Co, Ni, Cu). The Fermi level is set to zero.

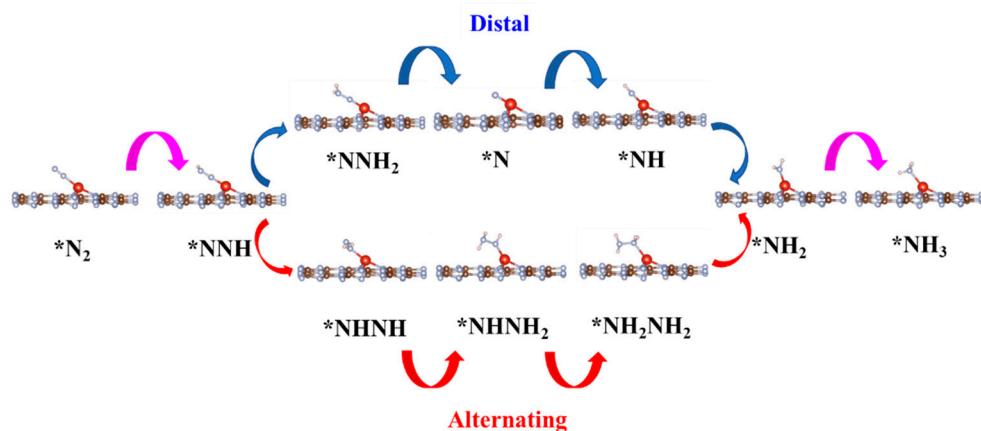


Figure S4. Optimized adsorption structures of intermediate via the alternating and distal mechanisms.

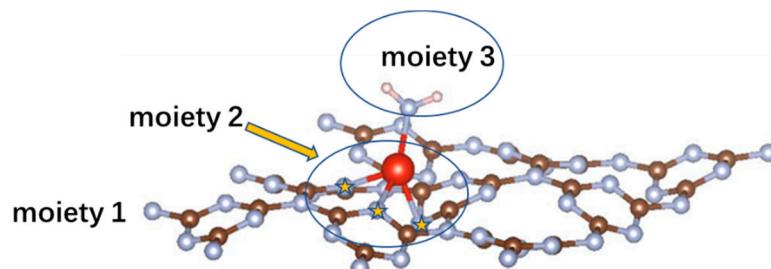


Figure S5. Diagram of the moiety 1(g-C₃N₄), moiety 2 (V-3N) and moiety 3 (the adsorbed intermediate N_xH_y).